NSN 5961-01-344-1711

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-344-1711 **Inclosure Material:** Glass and metal **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 835.0 breakdown voltage, dc **Current Rating Per Characteristic:** 11.60 amperes all primaries universal **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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